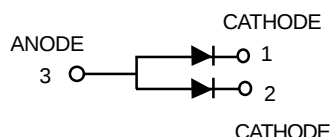
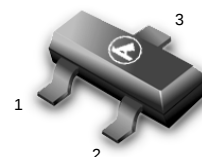


Monolithic Dual Switching Diodes



MMBD2835LT1
MMBD2836LT1



CASE 318-08, STYLE 12
SOT- 23 (TO-236AB)

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Reverse Voltage	MMBD2835LT1	V_R	Vdc
	MMBD2836LT1	75	
Forward Current	I_F	100	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board ⁽¹⁾	P_D	225	mW
$T_A = 25^\circ\text{C}$			
Derate above 25°C		1.8	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C/W}$
Total Device Dissipation	P_D	300	mW
Alumina Substrate, ⁽²⁾ $T_A = 25^\circ\text{C}$			
Derate above 25°C		2.4	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C/W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

DEVICE MARKING

MMBD2835LT1 = A3X; MMBD2836LT1 = A2X

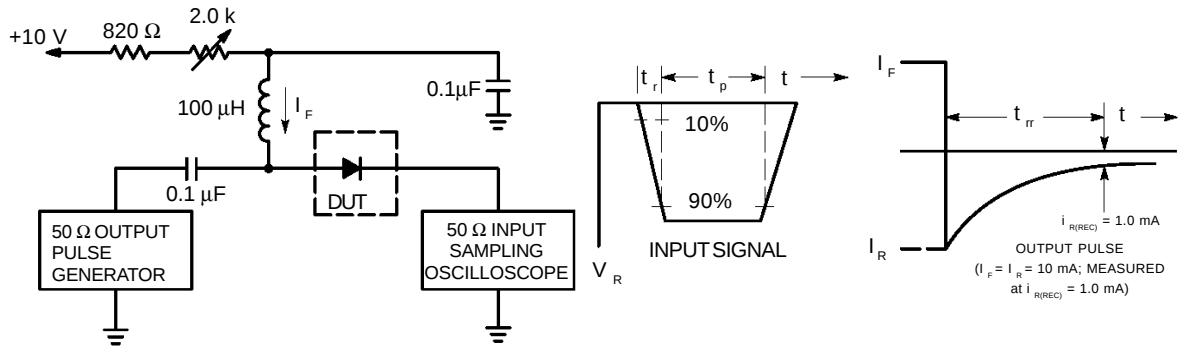
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (EACH DIODE)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Reverse Breakdown Voltage ($I_R = 100 \mu\text{Adc}$)	$V_{(BR)}$	35	—	Vdc
		75	—	
Reverse Voltage Leakage Current	I_R	—	100	nAdc
($V_R = 30 \text{ Vdc}$)	MMBD2835LT1	—	100	
($V_R = 50 \text{ Vdc}$)	MMBD2836LT1	—	100	
Diode Capacitance	C_T	—	4.0	pF
($V_R = 0, f = 1.0 \text{ MHz}$)				
Forward Voltage ($I_F = 10 \text{ mAdc}$)	V_F	—	1.0	Vdc
($I_F = 50 \text{ mAdc}$)		—	1.0	
($I_F = 100 \text{ mAdc}$)		—	1.2	
Reverse Recovery Time ($I_F = I_R = 10 \text{ mAdc}, I_{R(REC)} = 1.0 \text{ mAdc}$) (Figure 1)	t_{rr}	—	4.0	ns

1. FR-5 = $1.0 \times 0.75 \times 0.062 \text{ in.}$

2. Alumina = $0.4 \times 0.3 \times 0.024 \text{ in.}$ 99.5% alumina.

MMBD2835LT1 MMBD2836LT1



- Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current (I_F) of 10mA.
 2. Input pulse is adjusted so $I_{R(peak)}$ is equal to 10mA.
 3. $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit

CURVES APPLICABLE TO EACH CATHODE

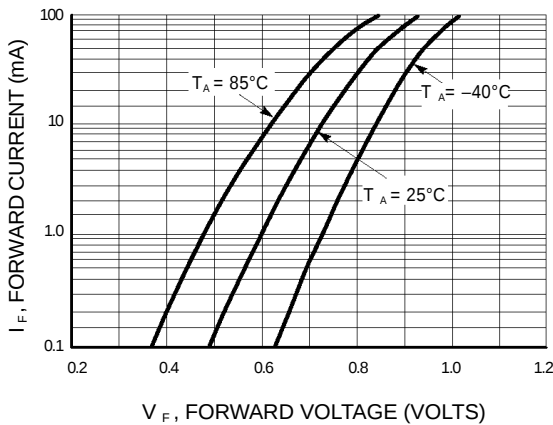


Figure 2. Forward Voltage

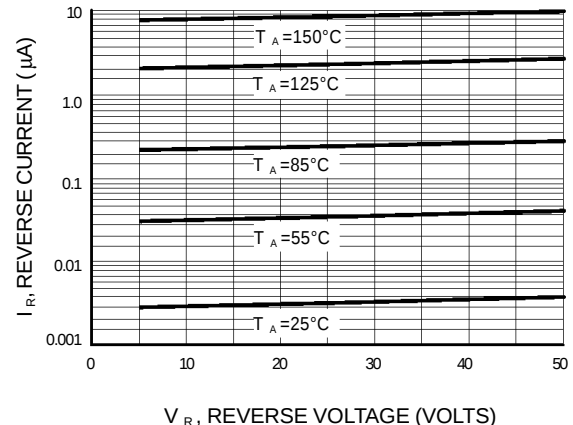


Figure 3. Leakage Current

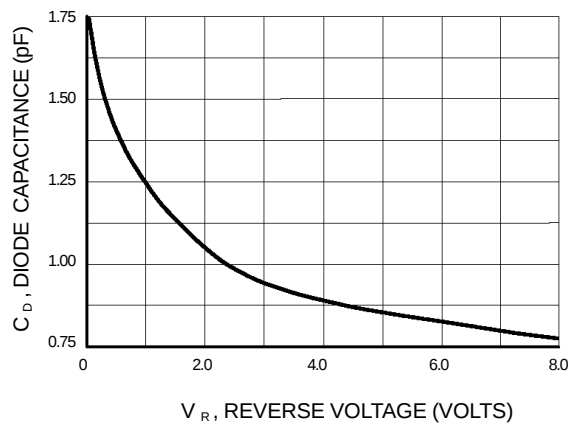


Figure 4. Capacitance